

v03.0608



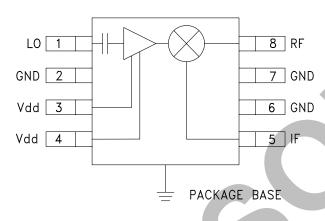
GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

Typical Applications

The HMC488MS8G / HMC488MS8GE is ideal for:

- · Basestations & Repeaters
- Access Points & Subscribers
- UNII, ISM, WLAN & WiMAX
- Point to Point/Multi-Point Radios
- VSAT Radio

Functional Diagram



Features

Low Conversion Loss: 7 dB

Double-Balanced Topology

Integrated LO Amplifier: 0 to +6 dBm Drive

Input IP3: +15 dBm

Single Supply: +5V @ 46 mA

MSOP8-G Package: 14.8 mm²

General Description

The HMC488MS8G(E) is an ultra miniature double-balanced mixer with integrated LO amplifier in an 8 lead plastic SMT MSOP8-G covering 4 - 7 GHz. This passive MMIC mixer integrates a GaAs Schottky diode quad, transformer baluns and a LO buffer on a single chip yielding a low conversion loss of 7 dB coupled with an input IP3 of +15 dBm. The LO buffer amplifier can be driven from 0 to +6 dBm and requires a single supply of +5V @ 46 mA. The device can be used as an upconverter, downconverter or bi-phase (de)modulator for a variety of point-to-point/multipoint, VSAT, telemetry or broadband WLAN applications.

Electrical Specifications, $T_A = +25^{\circ}$ C, IF= 100 MHz, Vdd= 5V

	LO = +2 dBm		LO = 0 dBm				
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF & LO		4 - 7			5 - 6		GHz
Frequency Range, IF	DC - 2.5		DC - 2.5			GHz	
Conversion Loss		7	9.5		8	10.5	dB
Noise Figure (SSB)		7			8		dB
LO to RF Isolation	25	30		27	32		dB
LO to IF Isolation	16	20		20	25		dB
IP3 (Input)		15			15		dBm
1 dB Gain Compression (Input)	5	8		6	9		dBm
Supply Current (Idd)		46	60		46	60	mA

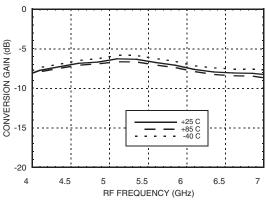


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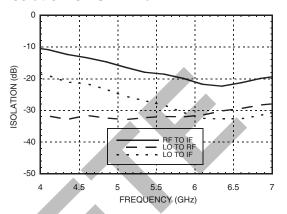


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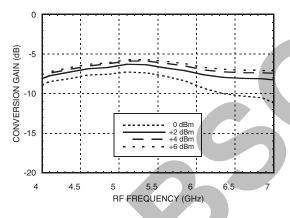
Conversion Gain vs. Temperature @ LO = +2 dBm



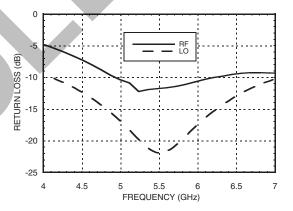
Isolation @ LO = +2 dBm



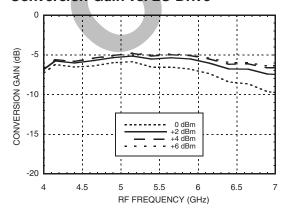
Conversion Gain vs. LO Drive



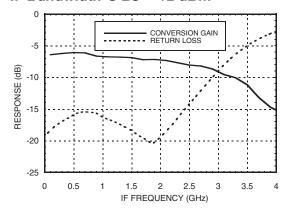
Return Loss @ LO = +2 dBm



Upconverter Performance Conversion Gain vs. LO Drive



IF Bandwidth @ LO = +2 dBm



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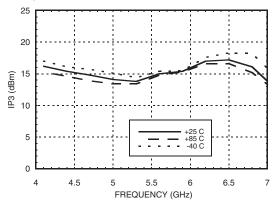
LO AMPLIFIER, 4 - 7 GHz



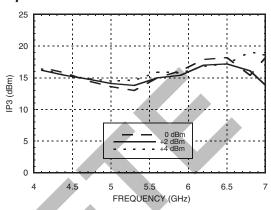
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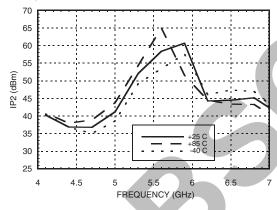
Input IP3 vs. Temperature @ LO = +2 dBm



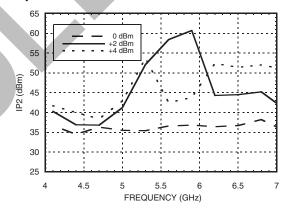
Input IP3 vs. LO Drive



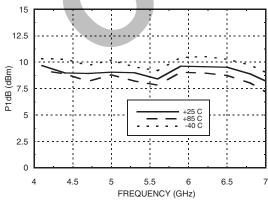
Input IP2 vs. Temperature @ LO = +2 dBm



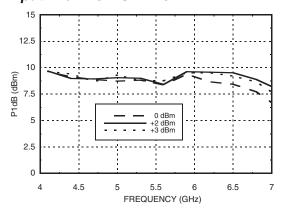
Input IP2 vs. LO Drive



Input P1dB vs. Temperature @ LO = +2 dBm



Input P1dB vs. LO Drive





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GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

MxN Spurious @ IF Port

	nLO				
mRF	0	1	2	3	4
0	xx	9	20	24	40
1	12	0	29	52	41
2	62	60	63	60	77
3	77	83	74	63	75
4	83	83	84	85	82

RF Freq. = 5.3 GHz @ -10 dBm LO Freq. = 5.2 GHz @ +3 dBm

All values in dBc relative to the IF power level.

Harmonics of LO

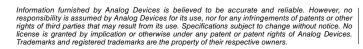
	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
5	32	18	42	52
5.2	32	19	62	56
5.4	31	23	52	59
5.6	31	26	43	64
5.8	31	26	40	57
6	31	27	43	51

LO = +3 dBm

All values in dBc below input LO level measured at RF port.

Typical Supply Current vs. Vdd

Vdd	Idd (mA)	
+4.75	45	
+5.0	46	
+5.25	47	
Mixer will operate over full voltage range shown above.		





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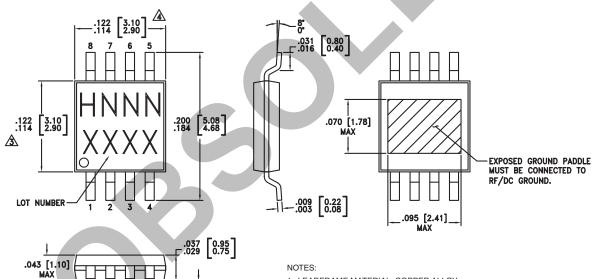
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Absolute Maximum Ratings

RF / IF Input (Vdd= +5V)	+13 dBm
LO Drive (Vdd= +5V)	+15 dBm
Vdd	+7 Vdc
Channel Temperature	150°C
Continuous Pdiss (T = 85°C) (derate 13.2 mW/°C above 85°C)	0.85 W
Thermal Resistance (channel to ground paddle)	75.5 °C/W
Storage Temperature	-65 to +150°C
Operating Temperature	-40 to +85°C
ESD Sensitivity (HBM)	Class 1A



Outline Drawing



NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

.015 0.38 TYP

.0256 [0.65] TYP

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC488MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H488 XXXX
HMC488MS8GE	HMC488MS8GE RoHS-compliant Low Stress Injection Molded Plastic		MSL1 [2]	H488 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX

.005 [0.13]



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Pin Descriptions

Pin Number	Function	Description	Interface Schematic	
1	LO	This pin is AC coupled and matched to 50 Ohms.	roo- - -	
2, 6, 7	GND	This pin must be connected to RF ground.	O GND	
3, 4	Vdd	These pins are power supply for LO amp. An external RF bypass capacitor (10,000 pF) is required.	Ag O O D P P P	
5	IF	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor. Choose value of capacitor to pass IF frequency desired. For operation to DC, this pin must not sink/source more than 40 mA of current or failure may result.	T T T T T T T T T T T T T T T T T T T	
8	RF	This pin is DC coupled and matched to 50 Ohms.	RF 0	

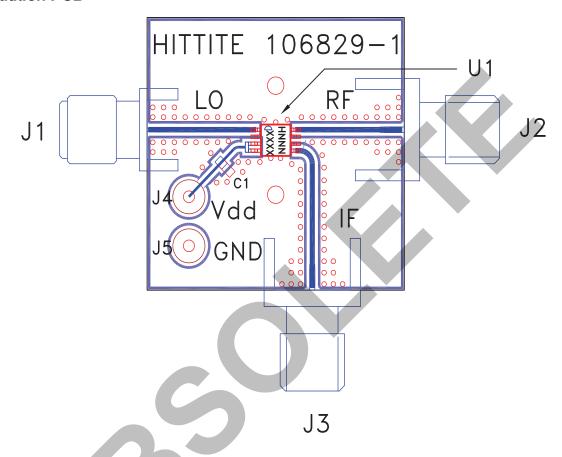


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Evaluation PCB



List of Materials for Evaluation PCB 108190 [1]

Item	Description		
J1 - J3	PCB Mount SMA RF Connector		
J4 - J5	DC Pins		
C1	10,000 pF Chip Capacitor, 0603 Pkg.		
U1	HMC488MS8G / HMC488MS8GE		
PCB [2]	106829 Evaluation Board, 1.000" x 1.000"		

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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Notes:

